TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74AC86P, TC74AC86F, TC74AC86FN, TC74AC86FT

QUAD EXCLUSIVE OR GATE

The TC74AC86 is an advanced high speed CMOS QUAD EXCLUSIVE OR GATE fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is includes on output buffer, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

- High Speed------t_{pd} = 4.4ns(typ.) at V_{CC} = 5V
- Low Power Dissipation $I_{CC} = 4\mu A(Max.)$ at $Ta = 25^{\circ}C$
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Symmetrical Output Impedance... $|I_{OH}| = I_{OL} = 24 \text{mA}(\text{Min.})$

Capability of driving 50Ω transmission lines.

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- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range $\sim V_{CC}$ (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74F86





IEC LOGIC SYMBOL



TRUTH TABLE



ABSOLUTE MAXIMUM RATINGS

Output Diode Current DC Output Current	Ι _{οκ} Ι _{ουτ}	± 50 ± 50	mA mA
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· ·			
Input Diode Current	Ι _{ικ}	± 20	mA
DC Output Voltage	V _{OUT}	-0.5~V _{CC} +0.5	V
DC Input Voltage	VIN	-0.5~V _{CC} +0.5	V
Supply Voltage Range	V _{cc}	-0.5~7.0	V
PARAMETER	SYMBOL	VALUE	UNIT

*500mW in the range of Ta = -40°C~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{cc}	2.0~5.5	V
Input Voltage	VIN	0~V _{cc}	V
Output Voltage	V _{OUT}	0~V _{cc}	V
Operating Temperature	T _{opr}	-40~85	°C
Input Rise and Fall Time	dt/dV	0~ 100 (Vcc = 3.3 ± 0.3V) 0~ 20 (Vcc = 5±0.5V)	ns / V

DC ELECTRICAL CHARACTERISTICS

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PARAMETER SYMB	SYMBOL			V _{cc}		Ta = 25°C		Ta = −40~85°C		UNIT
				(Ŭ)	MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	VIH		2.0 3.0 5.5	1.50 2.10 3.85		 	1.50 2.10 3.85		v	
Low - Level Input Voltage	VIL			2.0 3.0 5.5			0.50 0.90 1.65		0.50 0.90 1.65	v
High - Level Output Voltage V _{OH}		V _{OH} V _{IN} = V _{IH} or V _{IL}	I _{OH} = — 50µА	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	 	1.9 2.9 4.4		v
	V _{OH}		$I_{OH} = -4mA$ $I_{OH} = -24mA$ $I_{OH} = -75mA*$	3.0 4.5 5.5	2.58 3.94 —			2.48 3.80 3.85		v
Low - Level V _{OL} Output Voltage	V _{I N} =	I _{OL} = 50μA	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	v	
	VOL	V_{IH} or V_{IL}	$I_{OL} = 12mA$ $I_{OL} = 24mA$ $I_{OL} = 75mA*$	3.0 4.5 5.5			0.36 0.36 —		0.44 0.44 1.65	
Input Leakage Current	I _{IN}	$V_{IN} = V_{CC} \text{ or } GND$		5.5	_	-	±0.1	—	± 1.0	_
Quiescent Supply Current	I _{cc}	$V_{IN} = V_{CC} \text{ or } GN$	5.5	_	_	4.0	_	40.0	μΑ	

* : This spec indicates the capability of driving 50Ω transmission lines. One output should be tested at a time for a 10ms maximum duration.

AC ELECTRICAL CHARACTER		$L = 50 \mu r$, $R_L = 500 M_2$, I	npu	ι ι _r = ι _f =	51157				
PARAMETER	CYMPOL	TEST CONDITION		Ta = 25°C			Ta = −40~85°C		UNIT
	SYMBOL	V _{cc}	(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
Propagation Delay Time	t _{pLH} t _{pHL}	3.3 ± 5.0 ±			7.6 5.6	12.3 8.3	1.0 1.0	14.0 9.5	ns
Input Capacitance	C _{IN}			_	5	10	—	10	
Power Dissipation Capacitance	C _{PD} (1)			_	56	_	_	_	pF

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF , R_L = 500 Ω , Input t_r = t_f = 3ns)

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4 (per Gate)$

DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)

Unit in mm



SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)





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